

DESCRIPTION

The GC1500 series varactors are silicon abrupt junction devices. They offer the highest Q and lowest series resistance available in a 30 Volt silicon varactor.

This series of diodes meets RoHS requirements per EU Directive 2002/95/EC. The standard terminal finish is gold unless otherwise specified. Consult the factory if you have special requirements.

KEY FEATURES

- Highest Q
- Lowest R_s
- Large selection of capacitance values to chose from
- Low phase noise
- RoHS Compliant¹

¹ Most of our devices are supplied with Gold plated terminations. Other terminal finishes are available on request. Consult factory for details.

APPLICATIONS

The GC1500 series varactors are used for narrow to moderate bandwidth tuning. They are available in values appropriate for VHF through KU band frequencies. These devices are best used in low phase noise voltage controlled oscillators, low loss voltage variable filters and phase shifters.

Standard capacitance tolerance is $\pm 10\%$, other capacitance values and custom mechanical configurations are also available. All specifications shown are based on style 30 package and include 0.18 pF case capacitance. Consult package outline section of this catalog for other case styles available. Complete electrical and mechanical data is also provided.

APPLICATIONS/BENEFITS

- VHF to Ku Band Tuning
- VVF (Voltage Variable Filters)
- Phase Shifters

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)

Rating	Symbol	Value	Unit
Minimum Breakdown Voltage @10 μ A	V_B	30	V
Maximum Leakage Current @25 Volts	I_R	0.02 @ 25 °C 2.0 @125 °C	μ A
Operating Temperature	T_{OP}	-55 to +125	°C
Storage Temperature	T_{STG}	-65 to +150	°C
Thermal Coefficient of Capacitance @4 Volts	T_{CC}	300	ppm/ °C

IMPORTANT: For the most current data, visit www.MICROSEMI.com
 Specifications are subject to change, consult the factory for further information.



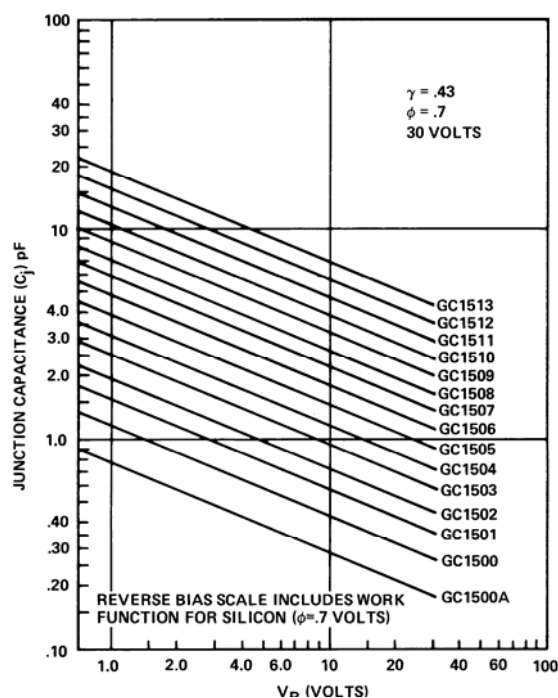
These devices are ESD sensitive and must be handled use using ESD precautions

ELECTRICAL CHARACTERISTICS @ 25° C

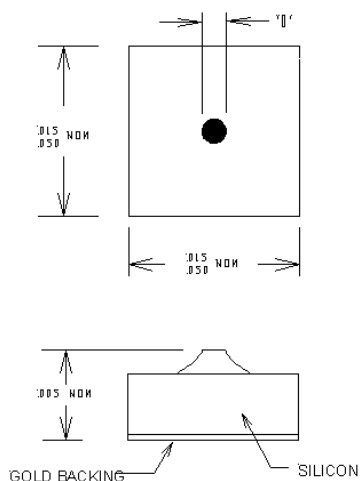
Model Number	C _{T-4} + / - 10%	Quality Factor ³ (Min)	Capacitance Ratio ² (Min)
	(Note 2) @ -4V (pF)	@-4V, 50 MHz	C _{T0} / C _{T-30}
GC1500A – 00 ⁴	0.4	5000	4.2
GC1500B	0.6	4000	3.0
GC1500	0.8	3900	3.3
GC1501	1.0	3800	3.4
GC1502	1.2	3800	3.4
GC1503	1.5	3600	3.5
GC1504	1.8	3500	3.5
GC1505	2.2	3500	3.7
GC1506	2.7	3300	3.7
GC1507	3.3	3100	3.8
GC1508	3.9	2700	3.9
GC1509	4.7	2600	3.9
GC1510	5.6	2600	4.0
GC1511	6.8	2400	4.0
GC1512	8.2	2200	4.0
GC1513	10.0	2200	4.2

Notes

- When ordering, specify the desired case style suffix to the model. (eg. GC1501 – 30)
- Capacitance values include a package capacitance of 0.18 pF. Capacitance is measured at F = 1 MHz.
- Q is calculated from:
 - $Q = 1 / 2\pi f R_s C_j$
 - R_s is measured using @ 1 GHz using transmission loss techniques.
 - Capacitance is measured at 1 MHz
- GC1500A is only available in chip form. (GC1500A – 00)

TYPICAL C_J VS REVERSE BIAS

GC1500 SERIES

OTHER PACKAGE STYLES AVAILABLE ON REQUEST
 CONSULT FACTORY FOR DETAILS

STYLE 00


- NOTES:
1. TOP CONTACT, CHIP SIZE, AND CHIP THICKNESS DEPENDS ON DIODE PARAMETERS. CONSULT FACTORY.
 2. TOP AND BOTTOM CONTACTS GOLD.

STYLE 30
